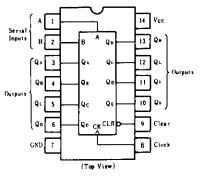
HD74LS164 .8-Bit Parallel-Out Serial-In Shift Registers

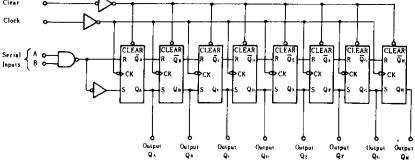
This 8-bit shift register features gated serial inputs and an asynchronous clear. The gated serial inputs (A and B) permit complete control over incoming data as a low at either (or both) input(s) inhibits entry of the new data and resets the first flip-flop to the low level at the next clock pulse, A high-level input enables the other input which will them determine the state of the first flip-flop. Data at the serial inputs may be changed while the clock is high or low, but only information meeting the setup requirements will be entered. Clocking occurs on the low-to-high-level transition of the clock input.

> Clear Clock

BLOCK DIAGRAM

PIN ARRANGEMENT





EFUNCTION TABLE

	Inpu	its		Outputs				
Clear	Clock	A	В	QA	Q	Qн		
L	×	×	×	L	L	L		
H	L	×	×	QAO	QBO	QHO		
Н	t	н	н	Н	QAn	QGn		
Н	t	L	×	L	QAn	QGn		
Н	t	×	L	L	QAn	QGa		

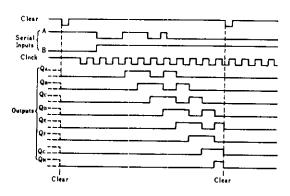
Notes) 1. H; high level, L; low level, X; irrelevant

2. †; transition from low to high level

3. QAo, QBO, QHO; the level of QA, QB, or QH, respectively, before the indicated steady-state input conditions were established.

4. Q_{An} , Q_{Gn} ; the level of Q_A or Q_G before the most-recent t transition of the clock; indicates a one-bit shift.

TYPICAL CLEAR, SHIFT, AND CLEAR SEQUENCES



RECOMMENDED OPERATING CONDITIONS

Item	Symbol	min	typ	max	Unit	
Clock frequency	frinck	0		25	MHz	
Clock pulse width	t _K (CK)	20	-		ns	
Clear pulse width	Ar(CLR)	20	-	_	ns	
Data setup time	tou	15	_	_	ns	
Data hold time	th .	5	-		ns	

ELECTRICAL CHARACTERISTICS ($Ta = -20 \sim +75^{\circ}C$)

Item	Symbol	Test Conditions		min	typ*	max	Unit
	VIH		2.0		****	v	
Input voltage	VII.					0.8	v
	Von	$V_{CC} = 4.75$ V, $V_{IH} = 2$ V, $V_{IL} = 0.8$ V, $I_{OH} = -400 \mu$ A		2.7	-	-	V
Output voltage			$I_{OL} = 4mA$	-		0.4	v
	Voi.	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.8 \text{V}$	$I_{0L} = 8 \text{mA}$			0.5	Ň
	Ін	$V_{CC} = 5.25$ V. $V_{I} = 2.7$ V			20	μA	
Input current	hь	$V_{CC} = 5.25 V, V_t = 0.4 V$			0.4	mA	
	h	$V_{CC} = 5.25 V, V_I = 7 V$			0.1	mA	
Short-circuit output-current	los	$V_{\rm CC} = 5.25 \mathrm{V}$	- 20		100	mА	
Supply current**	lee	$V_{CC} = 5.25 \mathrm{V}$		16	27	mA	
Input clamp voltage	Vik	$V_{\rm CC} = 4.75 \text{V}, I_{\rm IN} = -18 \text{mA}$				-1.5	V

* V_{CC}=5V, Ta=25°C

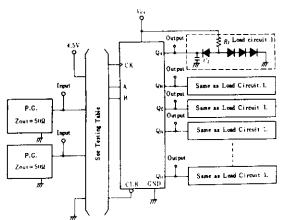
** I_{CC} is measured with outputs open, serial inputs grounded, the clock input at 2.4V, and a momentary grounded, then 4.5V applied to clear.

SWITCHING CHARACTERISTICS (VCC=5V, Ta=25°C)

Item	Symbol	Inputs	Outputs	Test Conditions	min	typ	max	Unit
Maximum clock frequency	fmax.	1	-		25	36		MHz
Propagation delay time	tpнi.	Clear	Q	$C_{l.} = 15 \mathrm{pF}, \ R_{l.} \approx 2 \mathrm{k} \Omega$		24	36	ns
	TP1.H	Clock	Q		-	17	27	ns
	tphi.	Clock	Q			21	32	ns

TESTING METHOD

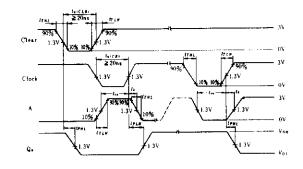
1) Test Circuit



- Notes) 1. Input pulse: $t_{TLH} \leq 15$ ns, $t_{THL} \leq 6$ ns, PRR = 1 MHz, (Clock, Clear), PRR=500kHz (A or B)
 - 2. C_L includes probe and jig capacitance. 3. All diodes are 1S2074 \bigoplus

2) Testing Table

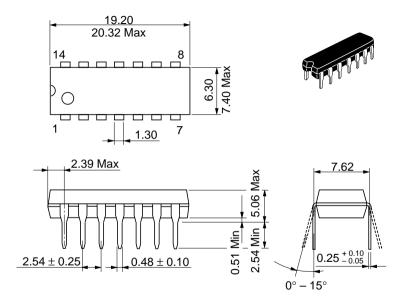
Waveform



Notes) QA output is illustrated. Relationship of serial input A and B data to other Q outputs is illustrated in the timing chart.

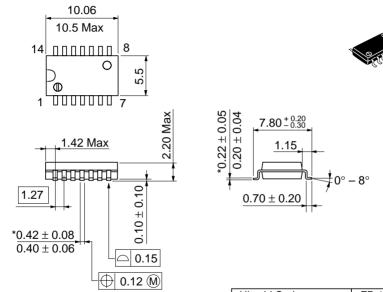
-	From input	Inputs				Outputs							
ltem	to output	CLR	СК	A	В	QA	Qн	Qc	QD	Qr	QF	Qc	Qн
fmax		4.5V	IN	IN	4.5V	OUT	OUT	OUT	OUT	OUT	OUT	OUT	OUT
telk	Clear→Q	IN	IN	IN	4.5V	OUT	OUT	OUT	OUT	OUT	OUT	OUT.	OUT
tphi.	CK → Q	4.5V	IN	IN	4.5V	OUT	OUT	OUT	OUT	OUT	OUT	OUT	OUT

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

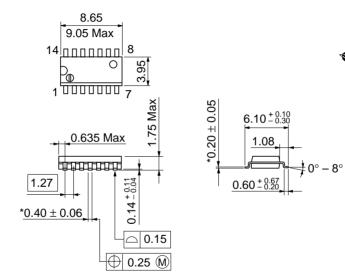
Unit: mm



*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.23 g

Unit: mm



Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.13 g

*Pd plating

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Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 NorthAmerica URL http:semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg Europe http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm http://www.hitachi.co.jp/Sicd/indx.htm Japan For further information write to: Hitachi Semiconductor Hitachi Europe GmbH Hitachi Asia Pte. Ltd. (America) Inc. Electronic components Group 16 Collyer Quay #20-00 179 East Tasman Drive, Dornacher Stra§e 3 Hitachi Tower San Jose,CA 95134 D-85622 Feldkirchen, Munich Singapore 049318 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Germany Tel: 535-2100 Tel: <49> (89) 9 9180-0 Fax: 535-1533 Fax: <49> (89) 9 29 30 00

 Fax: <49> (89) 9 29 30 00
 Hita

 Hitachi Europe Ltd.
 Hita

 Electronic Components Group.
 Taip

 Whitebrook Park
 3F,

 Lower Cookham Road
 Tun

 Maidenhead
 Tel:

 Berkshire SL6 8YA, United Kingdom
 Fax

 Tel: <44> (1628) 585000

 Fax: <44> (1628) 778322

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

HITACHI

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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